

isc N-Channel MOSFET Transistor

IXKC13N80C

• FEATURES

- High power dissipation
- Static drain-source on-resistance:
 $R_{DS(on)} \leq 290\text{m}\Omega @ V_{GS}=10\text{V}$
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

• APPLICATION

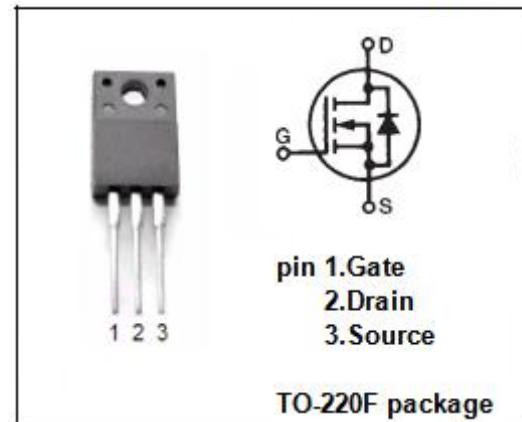
- DC/DC Converters
- High Current Switching Applications

• ABSOLUTE MAXIMUM RATINGS($T_a=25^\circ\text{C}$)

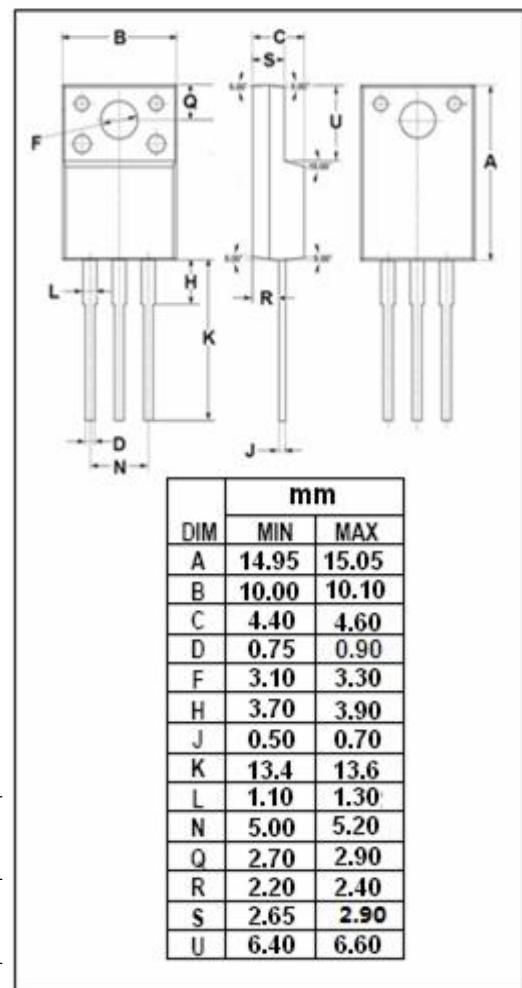
SYMBOL	PARAMETER	VALUE	UNIT
V_{DSS}	Drain-Source Voltage	800	V
V_{GS}	Gate-Source Voltage	± 20	V
I_D	Drain Current-Continuous	13	A
I_{DM}	Drain Current-Single Pulsed	9	A
T_j	Operating Junction Temperature	-55~150	$^\circ\text{C}$
T_{stg}	Storage Temperature	-55~125	$^\circ\text{C}$

• THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
$R_{th(j-c)}$	Junction-to-case thermal resistance	1	$^\circ\text{C}/\text{W}$



TO-220F package



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ELECTRICAL CHARACTERISTICS

 $T_c=25^\circ\text{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
BV_{DSS}	Drain-Source Breakdown Voltage	$V_{\text{GS}}=0\text{V}; \text{ID} = 250 \mu\text{A}$	800			V
$V_{\text{GS(th)}}$	Gate Threshold Voltage	$V_{\text{DS}}=V_{\text{GS}}; \text{ID} = 100 \mu\text{A}$	2		4	V
$R_{\text{DS(on)}}$	Drain-Source On-Resistance	$V_{\text{GS}}=10\text{V}; \text{ID} = 9\text{A}$			290	$\text{m}\Omega$
I_{GSS}	Gate-Source Leakage Current	$V_{\text{GS}} = \pm 20\text{V}; V_{\text{DS}}=0\text{V}$			± 100	nA
I_{DSS}	Drain-Source Leakage Current	$V_{\text{DS}}=V_{\text{DSS}}; V_{\text{GS}}=0\text{V}$			25	μA
		$V_{\text{DS}}=V_{\text{DSS}}; V_{\text{GS}}=0\text{V}; T_j = 125^\circ\text{C}$		125		
V_{SD}	Diode forward voltage	$I_F = 6.5\text{A}; V_{\text{GS}} = 0\text{V}$			1.2	V

NOTICE:

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